



N-Channel 30 V (D-S) Fast Switching MOSFET

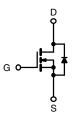
PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)			
30	0.00825 at V _{GS} = 10 V	15			
	0.00975 at V _{GS} = 4.5 V	13			

FEATURES

- Halogen-free According to IEC 61249-2-21 **Definition**
- Extremely Low Q_{gd} for Low Switching Losses
 TrenchFET[®] Power MOSFET
- New Low Thermal Resistance PowerPAK® Package with Low 1.07 mm Profile
- 100 % R_g Tested
- Compliant to RoHS Directive 2002/95/EC



- · High-Side DC/DC Conversion
 - Notebook
 - Server



N-Channel MOSFET

PowerPAK SO-8
6.15 mm 5.15 mm 2
Bottom View

Ordering Information: Si7342DP-T1-E3 (Lead (Pb)-free)

Si7342DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS	(T _A = 25 °C, unle	ss otherwise i	noted)			
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V_{DS}	30		V	
Gate-Source Voltage		V _{GS}	± 12			
Continuous Prain Current (T = 150 °C)a	T _A = 25 °C	I _D	15	9	А	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		12	7		
Pulsed Drain Current		I _{DM}	± 60		A	
Continuous Source Current (Diode Conduction) ^a		I _S	4.1	1.5		
Maximum Power Dissipation ^a	T _A = 25 °C	P _D	5	1.8	W	
	T _A = 70 °C		3.2	1.1		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	
Soldering Recommendations (Peak Temperature) ^{b, c}		-	260		C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Mariana la distributa (MOOFFT)	t ≤ 10 s	R _{thJA}	20	25	
Maximum Junction-to-Ambient (MOSFET) ^a	Steady State		53	70	°C/W
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	2.1	3.2	

- a. Surface mounted on 1" x 1" FR4 board.
- b. See solder profile (www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

Vishay Siliconix



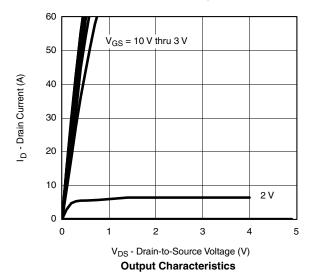
Parameter	Symbol	Test Conditions Min.		Тур.	Max.	Unit
Static			•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.6		1.8	V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			± 100	nA
Zero Gate Voltage Drain Current	,	V _{DS} = 30 V, V _{GS} = 0 V			1	
	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 ^{\circ}\text{C}$			10	μΑ
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			Α
Drain-Source On-State Resistance ^a	Б	V _{GS} = 10 V, I _D = 15 A		0.0066	0.00825	Ω
	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 13 A		0.0077	0.00975	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 15 A		65		S
Diode Forward Voltage ^a	V_{SD}	I _S = 2.9 A, V _{GS} = 0 V		0.73	1.1	٧
Dynamic ^b			•	•		
Input Capacitance	C _{iss}			1900		pF
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		530		
Reverse Transfer Capacitance	C _{rss}			120		
Total Gate Charge	Q_g			12.5	19	
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 15 \text{ A}$		3.9		nC
Gate-Drain Charge	Q_{gd}			2.1		
Gate Resistance	R_{g}		0.8	1.2	1.8	Ω
Turn-On Delay Time	t _{d(on)}			13	20	
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		8	13	1
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 10 V, R_G = 6 Ω		48	75	ns
Fall Time	t _f			13	20	1
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = 2.9 \text{ A}, dI/dt = 100 \text{ A}/\mu\text{s}$		36	55	

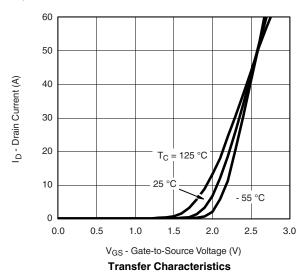
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

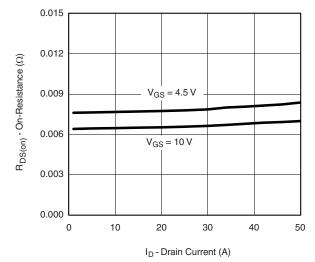




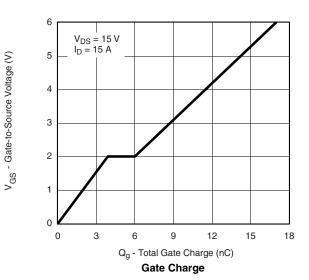


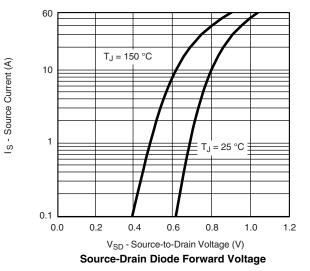


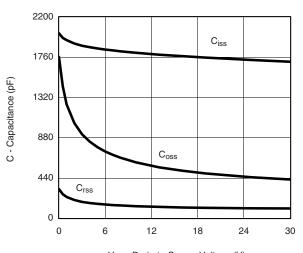
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



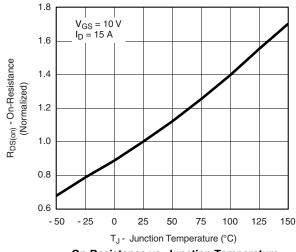
On-Resistance vs. Drain Current



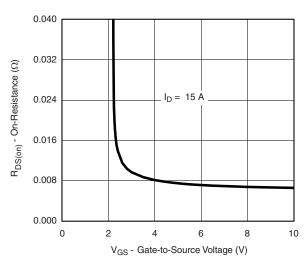




 V_{DS} - Drain-to-Source Voltage (V) $\label{eq:capacitance}$



On-Resistance vs. Junction Temperature

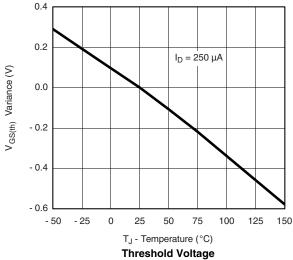


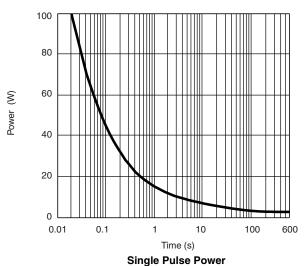
On-Resistance vs. Gate-to-Source Voltage

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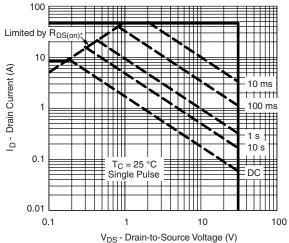
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



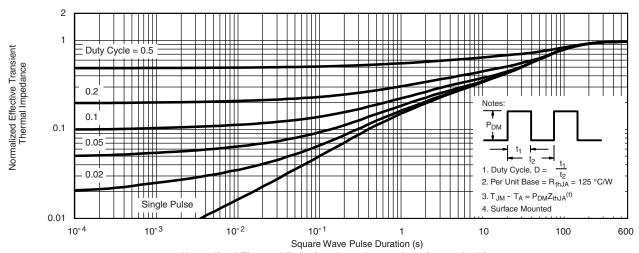


ld Voltage Single Pulse Por



* V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

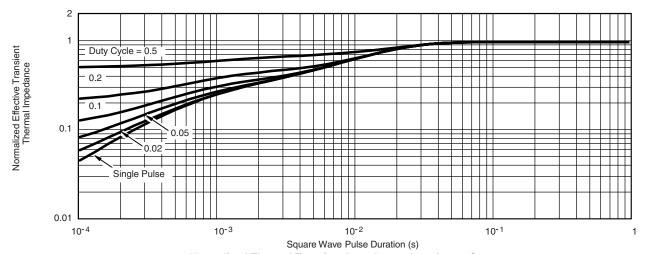
Safe Operating Area, Junction-to-Case



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

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